## **ESD Protection Diode Array**

### **Bi-directional ESD Protection for High-Speed Data Line**

The NUP4000 surge protection is designed to protect equipment attached to up to four high speed communication lines from ESD, EFT, and lightning.

#### Features:

- SO-8 Package
- Peak Power 400 W 8 x 20 μS
- ESD Rating: IEC 61000-4-2 (ESD) ±15 kV (air) ±8 kV (contact) IEC 61000-4-4 (EFT) 40 A (5/50 ns) IEC 61000-4-5 (lightning) 12 A (8/20 μs)
- UL Flammability Rating of 94 V-0
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **Typical Applications:**

- High Speed Communication Line Protection
- 15 V Data and I/O Lines
- Microprocessor Based Equipment
- LAN/WAN Equipment
- Servers
- Notebook and Desktop PC
- Serial and Parallel Ports
- Peripherals

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation 8 x 20 $\mu$ s @ T <sub>A</sub> = 25°C (Note 1)	P <sub>pk</sub>	400	W
Peak Pulse Current 8 x 20 μs @ T <sub>A</sub> = 25°C (Note 1)	I <sub>PP</sub>	10	A
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	– 55 to +150	°C
Lead Solder Temperature – Maximum 10 Seconds Duration	ΤL	260	°C

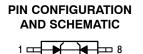
1. Non-repetitive current pulse 8 x 20  $\mu$ S exponential decay waveform

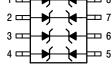


#### **ON Semiconductor®**

www.onsemi.com

SO-8 VOLTAGE SUPPRESSOR 400 WATTS PEAK POWER 15 VOLTS

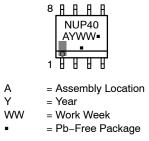






CASE 751

#### MARKING DIAGRAM



(Note: Microdot may be in either location)

#### ORDERING INFORMATION

	Device	Package	Shipping <sup>†</sup>
N	UP4000DR2G	SO-8 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

#### NUP4000

#### **ELECTRICAL CHARACTERISTICS**

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Working Voltage	V <sub>RWM</sub>	-	-	15	V
Reverse Breakdown Voltage @ I <sub>t</sub> = 1.0 mA	V <sub>BR</sub>	16.7	-	-	V
Reverse Leakage Current @ V <sub>RWM</sub> = 15 Volts	I <sub>R</sub>	N/A	-	1.0	μΑ
Maximum Clamping Voltage @ $I_{PP}$ = 1.0 A, 8 x 20 $\mu$ S	V <sub>C</sub>	N/A	-	24	V
Maximum Clamping Voltage @ $I_{PP}$ = 5.0 A, 8 x 20 $\mu$ S	V <sub>C</sub>	N/A	-	30	V
Maximum Peak Pulse Current	I <sub>PP</sub>	-	-	10	А
Junction Capacitance @ V <sub>R</sub> = 0 V, f = 1 MHz	CJ	-	-	75	pF

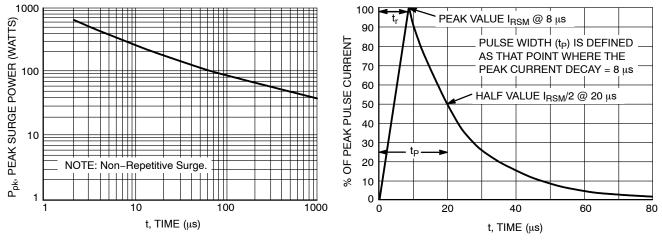


Figure 1. Pulse Width

Figure 2. 8  $\times$  20  $\mu s$  Pulse Waveform

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\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### STYLES ON PAGE 2

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#### SOIC-8 NB CASE 751-07 **ISSUE AK**

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STYLE 1: PIN 1. EMITTER COLLECTOR 2. COLLECTOR З. 4. EMITTER EMITTER 5. BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE, DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C З. REXT 4. GND 5. IOUT 6. IOUT IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. 4 COLLECTOR, #2 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6. BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE P-SOURCE 3 P-GATE 4. P-DRAIN 5. 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE 2. ANODE SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. CATHODE 8. STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC COMMON CATHODE/VCC 3 I/O LINE 3 4. 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 COMMON ANODE/GND 8. STYLE 26: PIN 1. GND 2 dv/dt ENABLE З. 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 GATE 2 З. SOURCE 2 4. SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

2. 3. 4. 5. 6. 7.	DRAIN, DIE #1 DRAIN, #1 DRAIN, #2 DRAIN, #2 GATE, #2 SOURCE, #2 GATE, #1 SOURCE, #1
2. 3. 4. 5. 6. 7.	INPUT EXTERNAL BYPASS THIRD STAGE SOURCE GROUND DRAIN GATE 3 SECOND STAGE Vd FIRST STAGE Vd
2. 3. 4. 5. 6. 7.	: SOURCE 1 SOURCE 2 GATE 2 DRAIN 2 DRAIN 2 DRAIN 1 DRAIN 1
3. / 4. / 5. ( 6. ( 7. (	
2. 3. 4. 5. 6. 7. 8.	SOURCE 1 GATE 1 SOURCE 2 GATE 2 DRAIN 2 MIRROR 2 DRAIN 1 MIRROR 1
2. 3. 4. 5.	5: LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND LINE 2 IN LINE 2 OUT COMMON ANODE/GND COMMON ANODE/GND LINE 1 OUT
STYLE : PIN 1. 2. 3. 4. 5. 6. 7. 8.	ILIMIT OVLO UVLO INPUT+ SOURCE SOURCE SOURCE

#### DATE 16 FEB 2011

STYLE 4: PIN 1. 2. ANODE ANODE ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 3. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 EMITTER, DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. 8. COLLECTOR/ANODE STYLE 28: PIN 1. SW\_TO\_GND 2. DASIC OFF DASIC\_SW\_DET 3. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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SOURCE 1/DRAIN 2

7.

8 GATE 1

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COLLECTOR, #1

COLLECTOR, #1

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